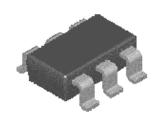
Analog Power AM3435P

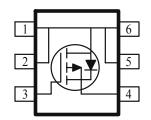
P-Channel 20-V (D-S) MOSFET

These miniature surface mount MOSFETs utilize High Cell Density process. Low $r_{DS(on)}$ assures minimal power loss and conserves energy, making this device ideal for use in power management circuitry. Typical applications are PWMDC-DC converters, power management in portable and battery-powered products such as computers, printers, battery charger, telecommunication power system, and telephones power system.

PRODUCT SUMMARY					
$V_{DS}(V)$	$r_{DS(on)} m(\Omega)$	$I_{D}(A)$			
-26.5	$56 @ V_{GS} = -4.5V$	-4.9			
	$80 @ V_{GS} = -2.5V$	-4.2			

- Low r_{DS(on)} Provides Higher Efficiency and Extends Battery Life
- Miniature TSOP-6 Surface Mount Package Saves Board Space
- High power and current handling capability





ABSOLUTE MAXIMUM RATINGS (T _A = 25 °C UNLESS OTHERWISE NOTED)						
Parameter		Symbol	Maximum	Units		
Drain-Source Voltage		V_{DS}	-26.5	V		
Gate-Source Voltage			±12	V		
C. C. A.	$T_A=25^{\circ}C$	_T_	-4.9			
Continuous Drain Current ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	1D	-4.0	A		
sed Drain Current ^b		I_{DM}	±20			
Continuous Source Current (Diode Conduction) ^a		I_S	-1.7	A		
D D	$T_A=25^{\circ}C$	D_	2.0	\mathbf{w}		
Power Dissipation ^a	$T_A=25^{\circ}C$ $T_A=70^{\circ}C$	L D	1.3	VV		
Operating Junction and Storage Temperature Range		T _J , T _{stg}	-55 to 150	°C		

THERMAL RESISTANCE RATINGS							
Parameter	Symbol	Maximum	Units				
M · I · · · a	4 <- F and	D	62.5	°C/W			
Maximum Junction-to-Ambient ^a	$t \le 5 \text{ sec}$	$R_{ heta JA}$	110	°C/W			

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Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- b. Pulse width limited by maximum junction temperature

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Donomoton	Carralt - 1	T. A.C. PA	Limits			TI!4	
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit	
Static							
Gate-Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = -250 \text{ uA}$	-0.7				
Gate-Body Leakage	I_{GSS}	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 12 \text{ V}$			±100	nA	
Zero Gate Voltage Drain Current	$I_{ m DSS}$	$V_{DS} = -21 \text{ V}, V_{GS} = 0 \text{ V}$			-1	uA	
Zero Gate Voltage Drain Current	1DSS	$V_{DS} = -21 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 55^{\circ}\text{C}$			-5	uA	
On-State Drain Current ^A	I _{D(on)}	$V_{DS} = -4.5 \text{ V}, V_{GS} = -4.5 \text{ V}$	-15			A	
Drain-Source On-Resistance ^A		$V_{GS} = -4.5 \text{ V}, I_D = -4.9 \text{ A}$			56	mΩ	
Drain-Source On-Resistance	r _{DS(on)}	$V_{GS} = -2.5 \text{ V}, I_D = -4.2 \text{ A}$			80	1115.2	
Forward Tranconductance ^A	g_{fs}	$V_{DS} = -10 \text{ V}, I_D = -4.9 \text{ A}$		11		S	
Diode Forward Voltage	V_{SD}	$I_S = 1.7 \text{ A}, V_{GS} = 0 \text{ V}$		-0.8		V	
Dynamic ^b							
Total Gate Charge	Q_{g}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$		25			
Gate-Source Charge	Q_{gs}	$V_{DS} = -10 \text{ V}, V_{GS} = -4.5 \text{ V},$ $I_{D} = -4.9 \text{ A}$		2.4		nC	
Gate-Drain Charge	Q_{gd}	I _D = -4.9 A		3.9		1	
Turn-On Delay Time	$t_{d(on)}$			22			
Rise Time	$t_{\rm r}$	V_{DD} = -10 V, R_L = 6 Ω , I_D = -1 A,		35		nS	
Turn-Off Delay Time	$t_{d(off)}$	VGEN = -4.5 V		45		113	
Fall-Time	t_{f}			25		ĺ	

Notes

- a. Pulse test: $PW \le 300us duty cycle \le 2\%$.
- b. Guaranteed by design, not subject to production testing.

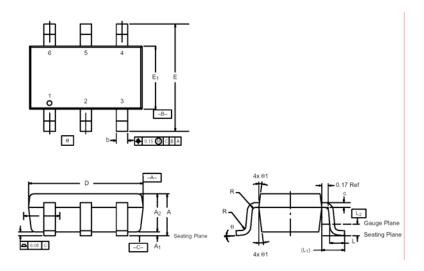
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Package Information

TSOP-6: 6LEAD



	MILLIMETERS			ı	INCHES		
Dim	Min	Nom	Max	Min	Nom	Max	
Α	0.91	-	1.10	0.036	_	0.043	
A ₁	0.01	_	0.10	0.0004	-	0.004	
A ₂	0.84	_	1.00	0.033	0.038	0.039	
b	0.30	0.32	0.45	0.012	0.013	0.018	
С	0.10	0.15	0.20	0.004	0.006	0.008	
D	2.95	3.05	3.10	0.116	0.120	0.122	
E	2.70	2.85	2.98	0.106	0.112	0.117	
E ₁	1.55	1.65	1.70	0.061	0.065	0.067	
е	1.00 BSC			0.0394 BSC			
L	0.35	_	0.50	0.014	ı	0.020	
L ₁	0.60 Ref			0.024 Ref			
L ₂	0.25 BSC			0.010 BSC			
R	0.10	_	-	0.004	_	_	
θ	0°	4°	8°	0°	4°	8°	
θ_1	7° Nom			7° Nom			